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ABOUT THE RELIABILITY OF EBSD MEASUREMENTS: DATA ENHANCEMENT

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Study of crystallography and PhD (Kossel technique) at Leipzig University. In 1990 hired for XRD powder diffraction investigations at Academy of Science. Since 1992 employed in BAM (Federal Institute for Materials Research and Testing, Berlin). Development of PowderCell, a free-available software for simulation of XRD powder patterns derived from crystal structure models (intuitive structure approximation in contrast to black-box software like Rietveld analysis). The first years in BAM examining residual stress and texture investigations by XRD. From 2002 working with EBSD, and since then organiser of annual German EBSD meetings. Between 2008 and 2011 sabbatical as global product manager and responsible for launch and development of CrystAlign, the EBSD system of Bruker. In 2017 the mineral nolzeite was named after him. In the same year, he became honorary professor for EBSD at TU Bergakademie Freiberg. Author and co-author of more than 90 publications.

1. ABSTRACT

An extensive set of information about the diffracting volume is carried by EBSD patterns: The crystal lattice, the reciprocal lattice, the crystal structure, the crystal symmetry, the mean periodic number of the diffracting phase, the source point from where it has been projected (projection centre), the crystal orientation, the sample topography (local tilt), the (preparation) quality or defect density of the crystal, and a possible pattern overlap, among others. Some of these types of information are used regularly in EBSD analyses; others are still waiting for a more widespread application. Despite the available wealth of information, the accuracy and precision of the data which are presently extracted from conventional EBSD patterns are often well below the actual physical limits. Using a selection of example applications, we will demonstrate the gain in precision, which is possible when using relatively low-resolution patterns with about 20,000 pixels only in combination with pattern matching approaches. In this way, fine details in a microstructure can be revealed which are otherwise hidden in orientation noise.

2. INTRODUCTION

Electron backscatter diffraction (EBSD) is a technique for a quantitative microstructure characterisation of crystalline materials in the scanning electron microscope (SEM). Standard applications of EBSD patterns are the determination of the phase distribution, the texture description, grain size, grain shape and grain boundary analysis, among others. New data processing tools are continuously developed, and these can help to improve the reliable interpretation of often very complex microstructural problems in materials science.

Because small misorientations (MO) can be important for the behaviour of materials [1-3], it is important to have a corresponding precision in EBSD orientation measurements. The computation of the MO can be performed by multiplying two orientation matrices only: $\Delta\mathbf{g}_{ij} = \mathbf{g}_i^{-1} \cdot \mathbf{g}_j$, from which the MO angle and axis can be determined.

A key factor for orientation and MO measurements is the angular resolution, which denotes with which precision a crystal orientation is derived from an EBSD pattern. Indirect techniques are common to determine the MO precision, e.g., the determination of MOs measured under comparable conditions at two positions in an undeformed grain. As these positions are presumed to have negligible MOs, the apparent MOs can be used to approximate an error of the experimental MO determination. From the according MO histogram, the mean, sometimes also the maxima, or the 95th percentile of the MO distribution are interpreted as alternative measures for the orientation error.

Of widespread use is kernel average misorientation (KAM) angle, which is the mean deviation of orientations determined around a selected pixel to the orientation of the pixel itself. Please note that this approach additionally reduces the real (relative) orientation variation by the

orientation averaging. Moreover, the definition of the kernel size for local averaging is different from software to software so that KAM angle distributions are only comparable if the same algorithm and parameters (maximum MO angle, number of classes, etc.) have been used. In the present paper, we use the KAM as calculated in MTEX [4]: the four surrounding pixels for a central pixel (top, bottom, right and left).

Approaches for an increase of the angular resolution in EBSD have been very early discussed, see e.g., [5]. From simple geometrical reasons, it can be expected that the acquisition of higher-resolved, i.e., less-binned EBSD patterns should be a straightforward way to increase the angular resolution of the orientation results. The practical benefit of a higher pattern resolution, however, can be lower than expected, cf. Fig. 1, taking into account a disproportionately higher measurement effort. In this context, it is unfortunate that the specific post-processing procedures in commercial “black-box” software are usually inaccessible. The graphs in Fig. 1 display the KAM angle distributions for maps derived from EBSD patterns with different image resolution, namely 160×115 and 320×230 pixels. As anticipated, the higher the image resolution the higher the angular resolution, i.e., the blue curve shifts to smaller misorientation angles. However, caused by the higher resolution and the demand for a comparable signal quality, the dwell time is quadrupled for 320×230 pixel patterns so that the achieved effective improvement appears disappointing. Please note that the red graph in Fig. 1 is also derived from low-resolved patterns, but collected with effectively the same total exposure time because of the application of frame averaging: $t_{320 \times 230} = 4 \text{ frames} \cdot t_{160 \times 115}$. The nearly same shape of blue and red graph suggest that there is only an apparent correlation between pattern and angular resolution, also taking into account that the red and blue curve were taken at different mapping positions. The similarity of the KAM results for the same measurement time but different pattern resolution indicates internal binning of the patterns to a similar effective resolution for the Hough based band detection, peak search, and indexing.

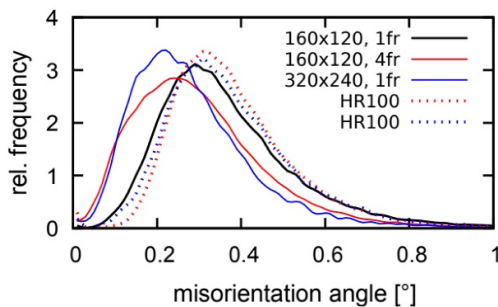


Figure 1. KAM angle distribution (polycrystalline GaP). Patterns with a size of 320×240 pixels deliver a slightly better angular resolution than 160×120 pixel patterns, but four frames (fr) averaged generate an equivalent distribution as the higher resolved patterns. HR100: indexing with Hough resolution 100 instead of the default value $HR = 60$.

The analysis discussed above has been performed using the default Hough resolution $HR = 60$ in the EBSD software (Bruker Esprit). It can be expected that an increase of the Hough space resolution HR should actually deliver a higher angular precision since it resolves the Hough

space with a considerably higher resolution. As can be seen in Fig. 1, however, an increase to $HR = 100$ results in a histogram which is effectively identical to the one performed in a quarter of time, cf. the identically coloured, dotted lines.

While the need for higher angular resolutions in EBSD is a permanent issue, it is interesting to observe the actual improvements in orientation resolution when higher resolution patterns are collected. In [6] patterns of 640×480 pixels and 128×96 pixels have been used for comparative measurements in deformed stainless steel. Related to the 16-times longer acquisition time for the non-binned patterns the achieved improvements are quite small. In [7] it is reported that the derived average GND density seems to be unaffected by pattern resolutions higher than 160×128 pixels. This result is possibly related to the software-internal pattern processing discussed above.

In [8, 9] the mean of the KAM distribution has been found only twice smaller for 640×480 pixel patterns compared to 128×96 pixel patterns (step size: 250 nm). This difference still decreases with increasing step size. For $3 \mu\text{m}$ step size, high-resolution patterns are only $\approx 5\%$ more precise than their low-resolution equivalent.

In [7] also the influence of the step size (map resolution) on GND and MO fluctuation has been investigated. In order to exclude the dependency of step size in the local deformation assessment, a parameter called the local gradient $G(L)$ was proposed [10].

3. ORIENTATION REFINEMENT BY PATTERN MATCHING

Pattern matching (PM) is an orientation refinement, which starts with a crystal orientation taken from a conventional EBSD system, and tries to find a more precise orientation description by optimising the match between the locally acquired experimental and in real-time simulated patterns. Depending on the required resolution, this process can be much more time consuming in comparison to the Hough-based orientation determination. However, the primary goal of pattern matching is not a further increase of measurement speed but a higher orientation precision. In this way, pattern matching approaches can be an additional tool for applications where conventional EBSD does not have enough resolution or fails completely.

3.1. Small MOs with high precision

As a first example, we selected a duplex steel sample, which contains austenite precipitates in a ferrite matrix formed during heat-treatment. The mapped area shown in Fig. 2 is smaller than the ferrite grains so that all precipitates are orientation variants of this specific ferrite grain. For materials engineering, the most accurate description of the orientation relationship as well as the

habit plane are of high interest since a direct correlation between both of them and the strength of the material is assumed. Therefore, a highly precise orientation measurement is desired in this case.

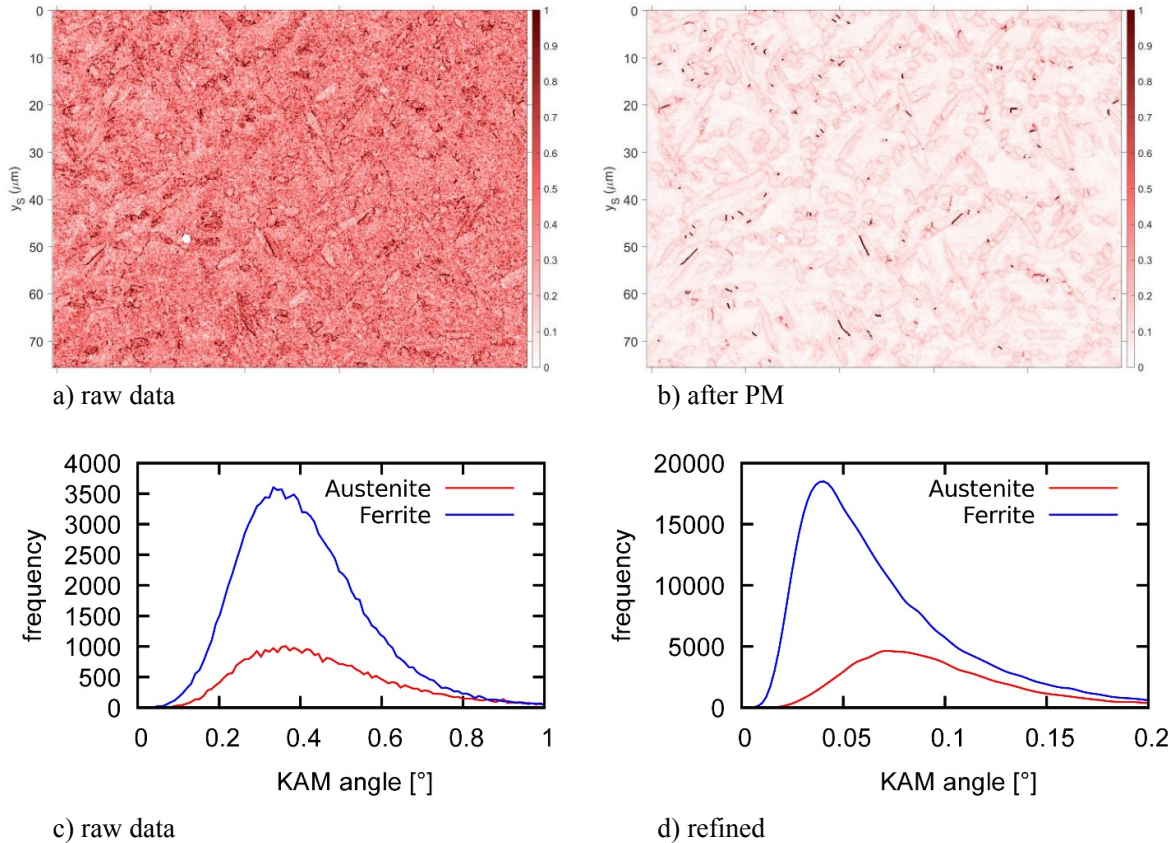


Figure 2. KAM angle maps derived from a) raw orientation data (ESPRIT 1.94, Bruker), and b) from refined orientation data after PM. The respective histogram plots are shown in c) and d). Please note the different KAM angle scales in c) and d).

The KAM angle maps in Fig. 2 already indicate a clear improvement compared to the manufacturer result. The reddish coloured map in Fig. 2a changes to a much lighter coloured image in Fig. 2b. The latter also enables a clear recognition of the austenite precipitates.

The respective histograms of the KAM angle reflect more quantitatively, how big the improvement finally becomes. The according maxima, mean values and 2σ ranges are listed in Table 1. It turns out that all values are at least four-times smaller, which we interpret as significant improvement of the orientation precision. This effect can be even seen in pole figures, which display the pole distribution of about 66,000 single austenite measurements. The scattering of the approximately displayed 400,000 dots is already small for the raw orientation data, but for the refined orientations the pole scattering is considerably reduced. Thus, the pole distribution looks sharper.

Table 1. Some characteristic parameters of the KAM angle distribution from Fig. 2. The difference between raw and refined data are roughly described by a factor 4.

		maximum	mean	$2\sigma \approx 90\%$
raw	Austenite	0.36°	0.43°	0.89°
	Ferrite	0.33°	0.39°	0.71°
refined	Austenite	0.08°	0.09°	0.20°
	Ferrite	0.04°	0.06°	0.16°

Beside the higher precision, PM has still another benefit. In about 200 from 268,000 cases the commercial EBSD system failed in the phase assignment, cf. the extra dots in the centre of one segment of the three-fold symmetric pole distributions in Fig. 3a. During PM the software realises the low correlation between the assumed phase and the locally acquired backscattered Kikuchi diffraction (BKD) pattern (EBSD patterns corrected by the background signal). A test with the alternative phase showed that patterns of ferrite fit better and the respective dots in Fig. 3b are missing.

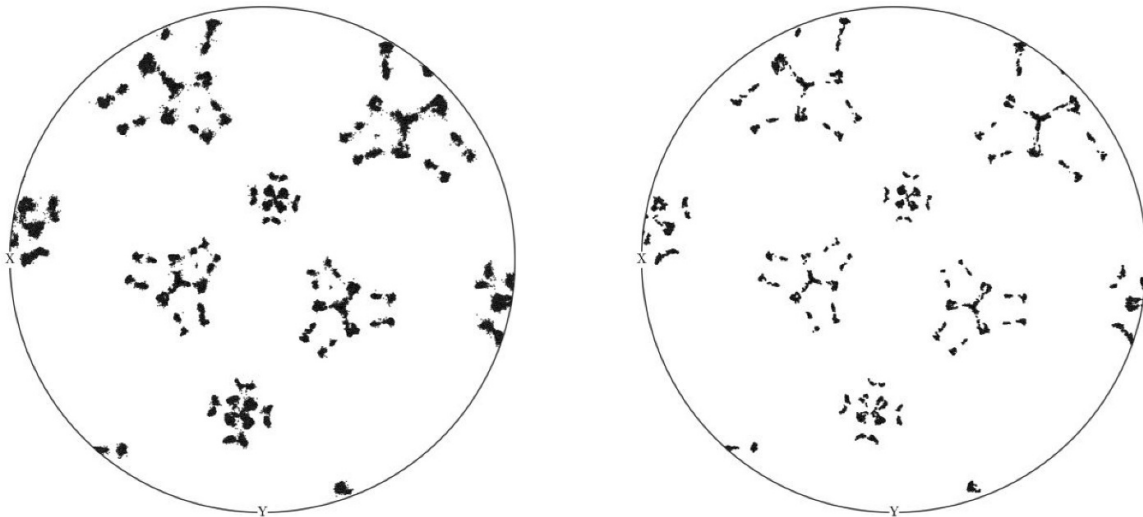


Figure 3. $\{011\}$ pole figures derived from raw orientations (a) and from orientation data after PM (b). The reduction of scattering from (a) to (b) is satisfying. The number of considered measured points differs since during refinement PM realizes that for $\approx 0.07\%$ of all measurements the phase was wrongly identified.

This example demonstrate that even EBSD patterns with a comparatively low resolution of only 160×115 pixels possess a high orientation precision. As a matter of course, the degree of improvement depends on many factors. For ideal materials like Si the precision can reach factors of up to 10. However, the higher the defect density the lower the improvement factor in the

KAM angle histogram since the histogram broadening is dominated by intrinsic misorientations and not by the orientation noise. Nevertheless, even in such cases the precision of PM is still incredible as visible on the microstructure of the next application.

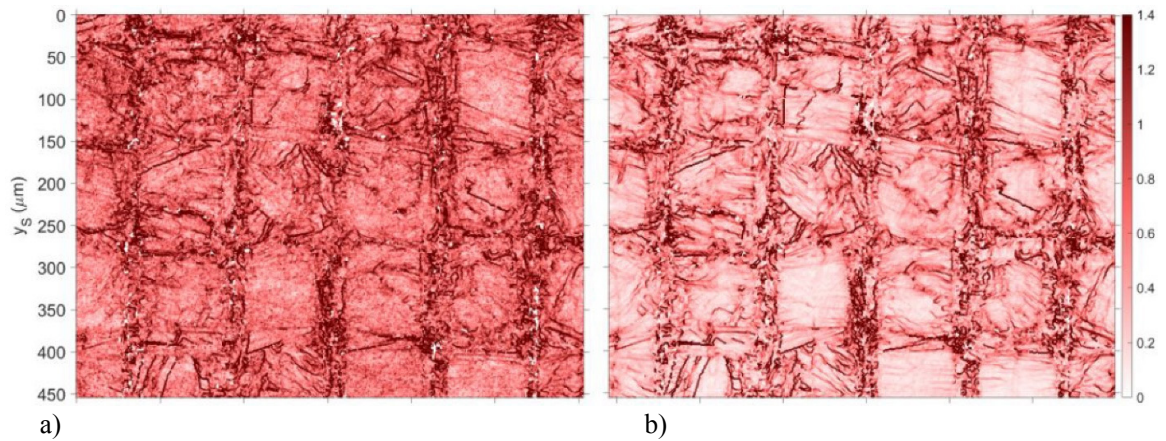
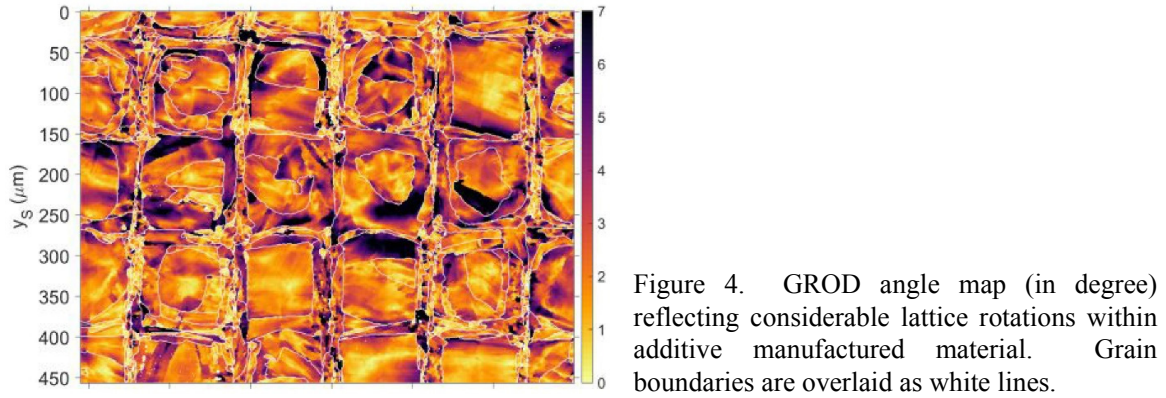
3.2. Big misorientations in high precision

The development of new materials or manufacturing processes often triggers a number of complications since previously used test and analytical procedures probably need to be adapted in order to discover new characteristic features and novel correlations between microstructure and observed properties. Additive manufacturing (AM) seems to be such a promising technology, which generates totally different and unusually complex and variable microstructures.

Typical characteristics of AM are repetitive remelting, fast local cooling and an extremely heterogeneous and complicated structure derived from the applied (sequential) printing-like technique. Thus, features like a periodically varying grain size distribution, or comparatively strong lattice rotations are not surprising. The gradient defined by the microscopic “lattice-like” periodic printing technique places higher demands on area selection (target preparation) as well as on test methods. Terms like “statistically relevant” will take on an entirely new dimension since “uniform” or “regular” are microstructure properties, which do not match to this technology anymore.

Nevertheless, as technique with high spatial resolution, EBSD is a recommendable analytical method. Only the angular resolution required for a precise evaluation of existing lattice rotations might be unsatisfactory. On the other hand, the formed microstructure in AM materials is characterised by comparatively big lattice rotations. A suitable visualisation is the grain reference orientation deviation (GROD) angle, which displays the deviation of the local orientation to the mean orientation of the grain, cf. Fig. 4. It represents a top view on the printed material. The periodicity in the checkerboard-like microstructure is consistent with the printing process but not identical since they are shifted against each other by one half. This means that the printing path is defined by the clearly visible boarder lines of the checkerboard and not by the centres of the visible squares. The scale bar in Fig. 4 suggests that 7° (or more) is not a rarely observed misorientation angle. In so far, high orientation precision is for such materials possibly not necessary?

To this aim, Fig. 5 compares the KAM maps based on conventional and refined orientation data. Despite huge lattice rotations accumulated during fast solidification, also both KAM maps display significant differences. The lower orientation noise in Fig. 5b enables a more authentic impression on information, which are, of course, also intrinsic in Fig. 5a. They only cannot be seen because of the high orientation noise. This difference suggests that a high orientation precision is also beneficial in case of big lattice rotations since they enable a reliable evaluation of low-angle boundaries, although the inhomogeneity of the square-shaped regions underlines the complexity of any interpretation of such processes. They are neither really translation symmetric (homogeneous) within the observed surface plane nor in depth.



As mentioned above, the high precision of PM is not that evident anymore in KAM angle distributions when other effects like a high intrinsic defect density dominate the curve shape, cf. Table 2. Maximum as well as mean for the refined data are still approximately twice that good, but the 2σ range practically does not change which has its reason in these big lattice rotations within grains.

Table 2. Some characteristic parameters of the KAM angle distribution derived from Fig. 5.

	maximum	mean	$2\sigma \approx 90\%$
raw	0.58°	0.70°	1.64°
refined	0.28°	0.40°	1.49°

A reliable detection of small misorientations is preferably interesting for a more advanced interpretation. A typical application is the density of geometrically necessary dislocation (GND) [11]. For the derivation of the curvature tensor a clear qualitative leap is apparent by PM, cf. Fig. 6. This gives at least some prospects regarding a more reasonable characterisation of high-gradient materials so that such data can significantly contribute to a better understanding and a successful correlation between microstructure and properties.

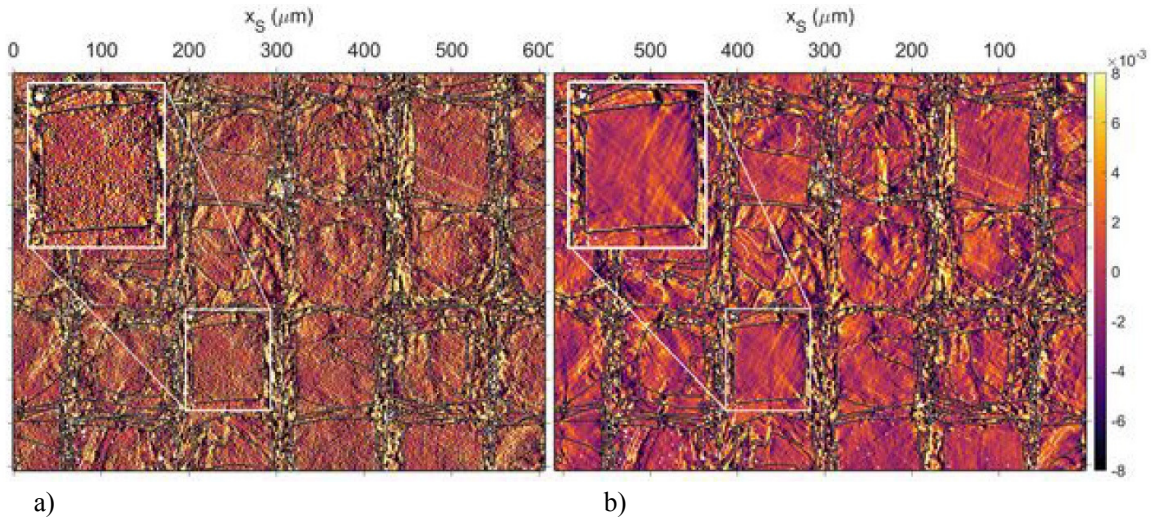


Figure 6. One of the six measurable components of the EBSD curvature tensor $\kappa - \kappa_{31}$ – which is used for the computation of the GND density. Both maps are derived from the identical patterns, only (a) shows the result from raw orientations, whereas in (b) the refined orientation data are used.

3.3. Pseudosymmetric crystal lattices

Phase transformation is a common phenomenon in material science. During this process, the atomic configuration at lower temperature often tends to lose the previously higher symmetry by small shifts of atoms. Although such movements do not practically vary the intensity of bands, they are not rarely associated with a slight deformation of the crystal lattice and may require a redefinition of the basis vectors which results in clearly different lattice parameters.

Quite frequently observed is the transition from a hexagonal close-packed arrangement of statistically distributed or already ordered elements to a further ordered configuration with longer translation periodicity of orthorhombic symmetry. As one representative Ni_3Sn_2 shall be discussed. The lattice relationships are shortly outlined in Table 3. The last row shows that during phase transformation the lattice effectively contracts in maximum only 1.7 %, which is from hearsay below the detection limit of EBSD, at least for low-resolution patterns as used above. To be on the safe side, for this investigation we increased the pattern resolution to

400 × 300 pixels. Later measurements, however, also demonstrated that this pseudosymmetric problem can be solved by EBSD patterns in standard resolution, i.e., by using patterns with about 20k pixels only.

Table 2. Lattice correlations of high (HT) and room temperature (RT) phase of Ni₃Sn₂. V_{uc} ... unit cell volume.

	Ni ₃ Sn ₂ (HT)	Ni ₃ Sn ₂ (RT)
symmetry	$P6_3/mmc$	$Pnma$
lattice parameters	$a_h = 4.146 \text{ \AA}$ $c_h = 5.253 \text{ \AA}$	$a_o = 7.124 \text{ \AA}$ $b_o = 5.195 \text{ \AA}$ $c_o = 8.152 \text{ \AA}$
V_{uc}	75.5 \AA^3	$304.9 \text{ \AA}^3 \approx 4 \cdot V_{uc_h}$
relationships		$a_o \approx \sqrt{3} \cdot a_h \quad (-0.8\%)$ $b_o \approx c_h \quad (-1.1\%)$ $c_o \approx 2 \cdot a_h \quad (-1.7\%)$

For Ni₃Sn₂ it is known that during cooling a single grain decomposes into numerous domains, which have crystallographically three totally different orientations of pseudosymmetric character. This means that despite non-equivalent orientations the respective diffraction signals look nearly identical. Therefore, the indexing fails and randomly one of the three pseudosymmetric orientations are selected. Notwithstanding that fact, the domains can be easily imaged by channelling-in contrast in SEM [12]. The question arises how reliable PM can discriminate between these three variants?

As Fig. 7a demonstrates by the three different colours, a separation of the pseudosymmetric orientations is possible and also reliable. However, compared to the standard PM the applied procedure works a bit different. As usual, the refinement starts with the orientation delivered from the EBSD system. This can be either an orientation based on the orthorhombic low-temperature unit cell, or an orientation based on the high-temperature hexagonal lattice. Both have drawbacks since the c-axis of the hexagonal phase is not parallel the c-axis of the low-temperature phase but to the b-axis, cf. Table 3. Therefore, several transformations are necessary, e.g., to be able to derive respective projections from the orthorhombic template pattern using orientations referring to a hexagonal cell. Easier appears a refinement based on pseudosymmetric data of the orthorhombic phase. However, now \vec{b} as monoclinic axis does not match the Euler-angle convention rotating around Z and X, respectively \vec{e}_3 and \vec{e}_1 . Notwithstanding these complications, the subsequent refinement compares the match for all

three pseudosymmetric solutions. The best is taken as most likely orientation description for this pattern. The briefly sketched procedure does not only deliver a qualitatively convincing distribution of the three variants, it also satisfies in a quantitative manner. This is first demonstrated in Fig. 7b by the KAM angle distribution. For the shown map, 95 % of all derived KAM angles are smaller than 0.14° , and the median is only 0.04° which is certainly the main impact of higher-resolved patterns analysed.

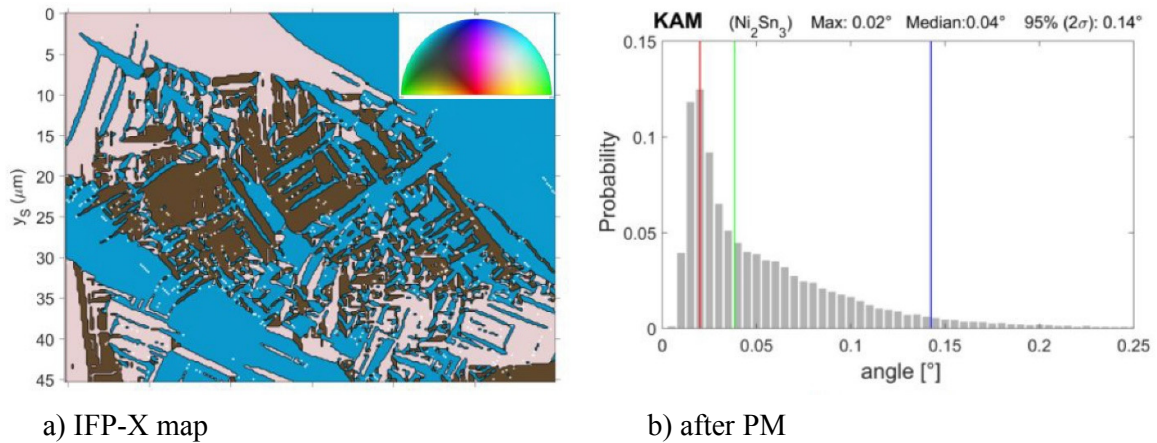


Figure 7. Orientation description of Ni_3Sn_2 -domains covering three pseudosymmetric orientations within a former single grain. The orientation description is based on the enantiomorphic symmetry group 222 [13].

Despite these small KAM angles, MO do not only result from orientation noise but also from real existing lattice rotations. For the imaging of the MO we will now not use only the GROD angle as in Fig. 4 but as additional information also the MO axis, which transfers the local orientation in the mean orientation of the grain by a rotation around the GROD angle. The maps displaying the GROD angles and axes are pictured in Fig. 8. The colour bar of the GROD angle encodes an angle variation between $0 \dots 1^\circ$. The colour distribution in Fig. 8a shows that large areas are characterised by GROD angles $< 0.2^\circ$. Despite these small angles, the map appears noise-poor which indicates a high orientation precision as suggested already by the KAM angle histogram in Fig. 7. The map also proves that within comparatively big grains higher GROD angles may occur. They mainly appear in correlation to other variants, which is not surprising since transformations with lattice distortions are assumed to cause stress, which may result in small lattice rotations.

The only information about MO angles already sometimes help to understand and imagine the reaction of a microstructure on processes like transformations. In many cases, the MO axis is of high interest as well, especially when t turns out that the directional distribution is inhomogeneous. If no correlation to the crystal symmetry is assumed, a rotation direction

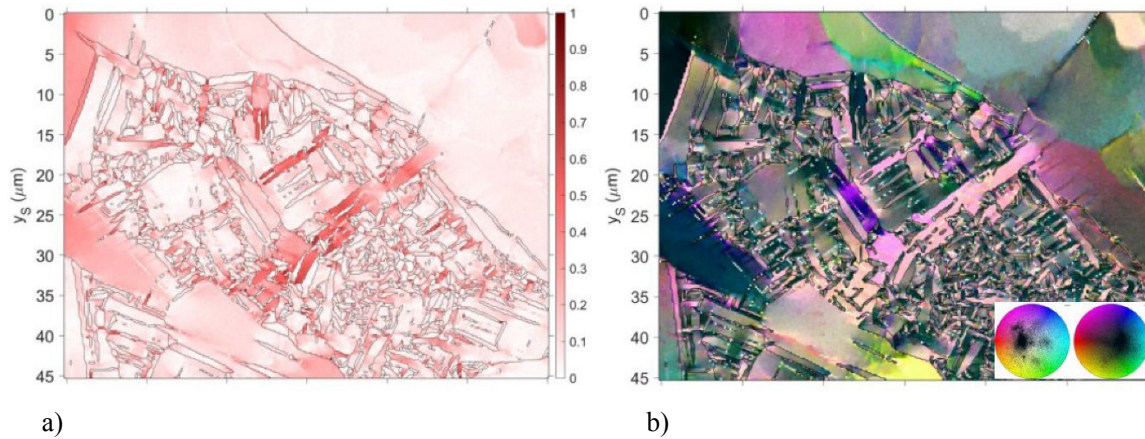


Figure 8. Grain reference orientation deviation (GROD) displayed as rotation angle (a) and as rotation axis (b). The inset image in (b) displays the MO axes distribution as stereographic projection of the two hemispheres.

colouring of the entire projection sphere needs to be considered, cf. the inset image in Fig. 8b. Many directions form a point cloud within the upper hemisphere (left) displaying as well the colour key. In contrast to the pure MO angle presentation, the colouring of the MO axis results in clearly higher colour contrasts. Please note that small MO angles commonly result in a considerable uncertainty of the MO axes. In this respect, the comparatively low colour fluctuation in Fig. 8b surprises. In any case, it is a further indication for the high orientation precision achievable with PM.

Both information, MO axis and angle, can be processed together when the used colour key is compressed in a way that for each specific grain the orientation variation is used to define the colour key size. Then identical MO angles are differently coloured when their MO axes varies. Such colouring is given in Fig. 9.

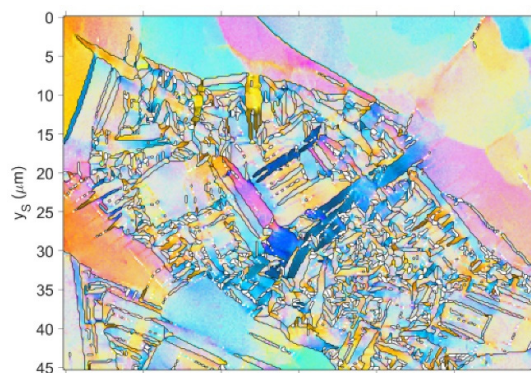


Figure 9. MO angle and axis from Fig. 8 encoded by a heavily compressed IPF-colour key. The orientation spread (polar angle) needs to be manually adapted.

Please note that the centre of gravity of the (compressed) colour key is defined by the mean orientation of each particular grain. The deviation (GROD angle as well as GROD axis) finally decides about the assigned colour. The disadvantage of this presentation tool is that an interpretation is only qualitatively possible since the definition of each colour depends on the compression applied.

Another domain-forming phase is perovskite. It is in fact a materials class, which is characterised by numerous phase transitions describing different subgroup relationships. Thus, beside the ideal cubic structure type, for all crystal systems down to triclinic phase descriptions can be found in databases. However, most of the listed phase descriptions are so similar that even X-ray powder diffraction as standard tool for phase discrimination is overstrained. Since the ability to distinguish between phases is much smaller for EBSD, any attempt to try this for pseudo-cubic perovskite is doomed to failure. A safe option is to use channelling-in contrast in SEM, or FSE images to recognise non-cubic perovskites by the characteristic herringbone structure, cf. Fig. 10. This is indisputable evidence that a perovskite is of no cubic symmetry and the lattice is slightly distorted. Figure 10 displays a bimodal microstructure of coarse BaTiO_3 -crystals embedded in a fine-grained matrix. The most often used approach in case of domains is a tetragonal distortion described by a $c = a$ ratio very close to 1.

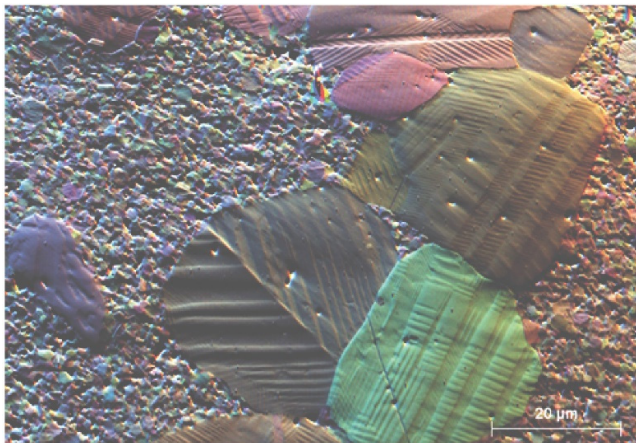


Figure 10. Fore-scattered electron image of a BaTiO_3 ceramic reflecting the characteristic herringbone structure. Please note the different colours of the grains whereas the domains do not considerably vary in colour but only in topography.

EBSB investigations prove that all BKD patterns can be easily indexed using a cubic crystal description. A single grain is then reflected as uniform crystal, possibly with a thin twin lamella, cf. for two of the four biggest grains in Fig. 10. In contrast, the attempt to index the patterns by a tetragonal phase description results in a more or less random selection of pseudosymmetric orientation solutions, as reported already for Ni_3Sn_2 . Sometimes the indexing delivers a preferable selection of an orientation solution for a few domains, but after rotating the sample by a few degrees only this preferred orientation selection disappears so that it is assumed to be an artefact of the applied band detection.

For PM we used a similar approach as briefly sketched for Ni_3Sn_2 , only that now all axes are consistent ($\vec{c}_{cub} \parallel \vec{c}_{tet} \parallel \vec{e}_3$), and only three pseudosymmetric solutions exist. The IPF-map in Fig. 11a proves that obvious misinterpretations do not occur. On the first glance, domains are uniformly indexed in a way that appears reasonable. However, a comparison with FSE images raises at least tentative doubts that the displayed unambiguousness in grain recognition is totally correct. The reason for qualms is the discrepancy between the numerous domains visible in FSE images and the apparent uniformity in the IPF map. In other words, the big domains look too uniform.

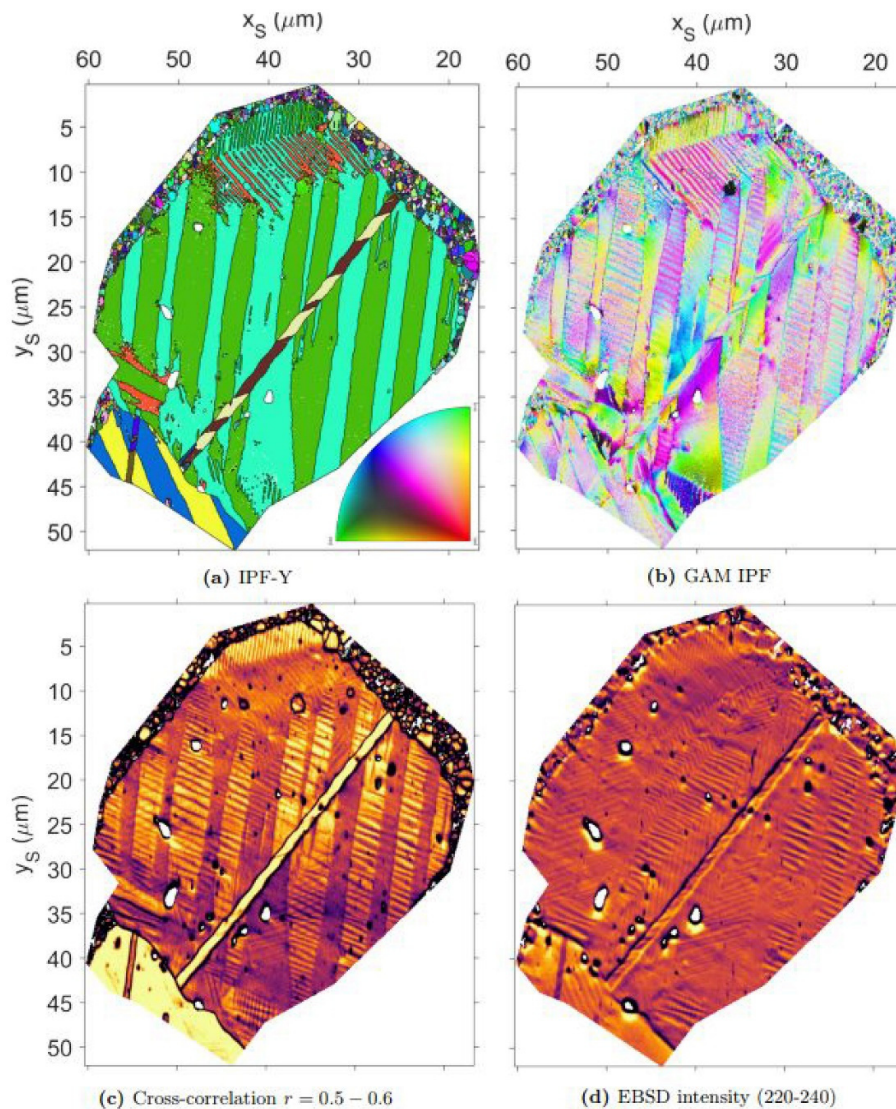


Figure 11. Orientations in a tetragonally assumed BaTiO_3 derived by PM and displayed as IPF-Y map. For the sake of clarity, grain boundaries are displayed as black lines (a). The intragranular misorientations are imaged in (b) by a compressed IPF-colour key, which displays systematic orientation variations within uniformly assumed domains in (a). In order to compare the information content the cross-correlation coefficient (c) and the variation in overall intensity derived from the EBSD patterns (d) are shown as well.

According to the doubts, further investigations of possible MOs discover a systematic orientation modulation, which suggests a correlation to the domains visible in FSE images like in Fig. 10. Despite the comparatively noisy signal, the modulation in form of parallel and practically equidistant stripes are well visible, see Fig. 11b. It is, however, conspicuous that there is no overall correlation. Fortunately, the differing regions accidentally correlate with the four biggest pores visible in the maps. Whereas in Figs. 11b and 11c the slope of the faintly visible, thin stripe are uniform from left top to right bottom, in Fig. 11d they are reverse. Due to this, the question is posed more and more often whether for the different maps in Fig. 11 the identical information from EBSD patterns is used. Figures 11a and 11b are based on the derived orientation solution only. Figure 11c represents the map, which indicates the degree of match used for Figs. 11a and 11b. Brighter colours indicate a better correlation whereas darker colours suggest that the applied PM resulted in a lower r -value. Reasons for the signal differences in Fig. 11c may be related to the orientation description or to an unfortunately selected phase description having an imperfect $c = a$ ratio. The map in Fig. 11d, however, is mainly triggered from the background intensity. Since the chemical composition is uniform, only channelling-in and topography are the main influencing factors. The signal in Fig. 11d is formed in higher depths so that we assume that the different slope has its reason in different information depths of BKD and background signal.

There is still another factor, which might considerably influence the angular resolution: the sample tilt in combination to the domain alignment. For different alignments in depth the interaction volume reacts in a smearing which fits to the nearly homogeneously but darker coloured domains in Fig. 11c. Domains between show clearly higher r -values, which suggests that these domains are favourably aligned and the electron probe does not average differently aligned domains as in the neighbourhood. The darker stripes are explainable by thin subdomains, which produce an overlaid signal of two different but pseudosymmetric orientations. The impact of the spatial resolution at tilted sample surfaces can be also seen at the upper part of the crystal, cf. Fig. 11c. There, a herringbone structure of very fine domains has been discovered by EBSD. All different domains can be distinguished but the signal for the nearly vertically aligned domains at the top is obviously of much higher quality since in Fig. 11c they show higher r -values than the domains directly below in the image.

4. SUMMARY AND CONCLUSIONS

Using a few selected examples, we tried to demonstrate the potential of low-resolution (10,000 - 20,000 pixels) EBSD patterns regarding an improvement of orientation precision. In order to circumvent the unknown image processing of high-resolved patterns in the manufacturer software, pattern matching (PM) of stored pattern to dynamical simulations has been used. The orientation data derived from the low-resolution EBSD patterns are already of higher precision than comparable investigations based on higher resolved patterns with Hough-based orientation determination. It has been shown that a higher precision can be useful for the investigation of

materials with different levels of deformation. Pattern matching also seems to be the approach of choice if highest precision is required, e.g., in case of a discrimination of pseudosymmetric orientation solutions.

While combination of higher-resolved patterns and pattern matching can improve the orientation precision still more, also other influences start to become important, including varying lattice parameter ratios, the correct projection centre position, the possible pattern distortions caused by local magnetic or electric fields, and the effective electron energy, for example.

5. ACKNOWLEDGEMENTS

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